NSN 5961-01-372-7319

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| Internal Configuration: |
|---|
| Point contact |
| Semiconductor Material: |
| Silicon |
| Voltage Rating In Volts Per Characteristic: |
| 65.0 breakdown voltage, collector-to-emitter, base open |
| Current Rating Per Characteristic: |
| 300.00 milliamperes source cutoff current |
| Power Rating Per Characteristic: |
| 3.0 watts small-signal input power, common-collector absolute |
| Special Features: |
| Junction pattern arrangement: pnp |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |
| A110a0 |
| |